TECHNICAL DATA DATA SHEET 4505, REV. -

POWER SCHOTTKY RECTIFIER Low Reverse Leakage

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra Low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	100	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle, rectangular wave form	15	A
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine wave (per leg)	280	А
Non-Repetitive Avalanche Energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}$, $I_{AS} = 1.3 \text{A}$, $L = 40 \text{mH}$ (per leg)	27	mJ
Repetitive Avalanche Current	I _{AR}	I_{AS} decay linearly to 0 in 1 μs f limited by T_J max V_A =1.5 V_R	1.3	Α
Thermal Resistance	R_{thJC}	Per Package	0.85	°C/W
Max. Junction Temperature	Τ _J	-	-65 to +200	°C
Max. Storage Temperature	T_{stq}	-	-65 to +200	°C

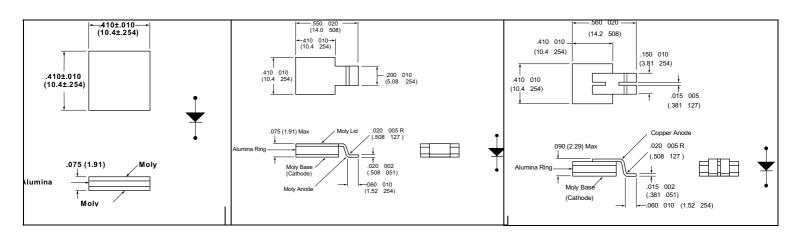
Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 15A, Pulse, T _J = 25 °C (per leg) measured at the leads	0.84	V
	V _{F2}	@ 15A, Pulse, T _J = 125 °C (per leg) measured at the leads	0.68	V
Max. Reverse Current	I _{R1}	$@V_R = 100V$, Pulse, $T_J = 25 ^{\circ}C$ (per leg)	0.35	mA
	I _{R2}	@ V_R = 100V, Pulse, T_J = 125 °C (per leg)	8.0	mA
Max. Junction Capacitance	Ст	$@V_R = 5 \text{ V}, T_C = 25 \text{ °C}$ $f_{SIG} = 1 \text{ MHz},$ $V_{SIG} = 50 \text{mV (p-p) (per leg)}$	500	pF

Due to the nature of the 100V Schottky devices, some degradation in t_{rr} performance at high temperatures should be expected, unlike conventional lower voltage Schottkys.

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Mechanical Dimensions: in inches / mm

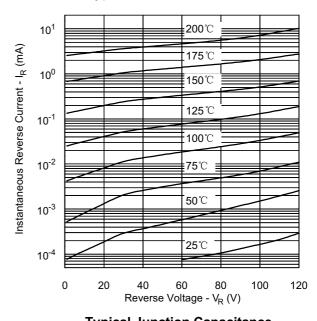


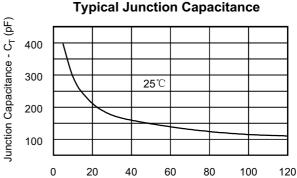
SHD-3A SHD-3B

Typical Forward Characteristics

10¹ 200℃ 175℃ Instantaneous Forward Current - I_F (A) 10⁰ 125℃ 25℃ 10⁻¹ 10⁻² 0.2 0.1 0.3 0.4 0.5 0.6 0.7 0.8 Forward Voltage Drop - V_F (V)

Typical Reverse Characteristics





Reverse Voltage - V_R (V)

Vf Curves shown are for die only.

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TECHNICAL DATA

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